## **INFORMATION DISCLOSURE CITATION**

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Atty. Docket No.	04329.2802-01000	Appln. No.	10/698,456	10
Applicant	Mari INOUE			APR 0 1 2004 is
Filing Date	November 3, 2003	Group:	To be Assigned	.5
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Examiner Initial*	Document Number	Issue Date	Name	Class	Sub Class	Filing Date If Appropriate
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FOREIGN PATENT DOCUMENTS							
		Document Number	Publication Date	Country	Class	Sub Class	Translation Yes or No
AC		Japanese Patent Application KOKAI Publication No. 2000-20564	01/21/2000	Japan	,		NO
AR		Korean Patent Application Publication No. 2000-23031	04/25/2000	Korea			NO
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Form PTO 14	Patent and Trademark Office - U.S. Depar	rtment of Commerce
*Examiner:	Initial if reference considered, whether or not citation is in conformance with MPE through citation if not in conformance and not considered. Include copy of this for communication to applicant.	
Examiner	Date Considered H-5-C	95

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Atty. Docket No.	04329.2802-01	Appln. No.	n/a	
Applicant	Mari INOUE			
Filing Date	November 3, 2003	Group:	n/a	

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Examiner	E. Dorasco	Date Considered 4-5-05
*Examiner:	Initial if reference considered, whether or r	not citation is in conformance with MPEP 609; draw line not considered. Include copy of this form with next
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